

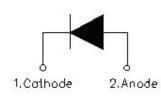
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SDUR60Q60W ULTRAFAST RECTIFIER



Circuit Diagram



Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Plastic Material has UL Flammability Classification
 94V-O
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Symbol Condition		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=70°C, rectangular wave form	60	A
Peak One Cycle Non-Repetitive Surge Current	IFSM	8.3ms, Half Sine pulse	400	А

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	0.34	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

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Electrical Characteristics:

Characteristics	aracteristics Symbol Condition		Тур.		Units
Forward Voltage Drop*	V _{F1}	@ 30A, Pulse, TJ = 25°C @ 60A, Pulse, TJ = 25°C	1.9 2.3	- 2.4	V
	V _{F2}	@ 30A, Pulse, T _J = 125°C	1.6	-	V
	V _{F3}	@ 30A, Pulse, T _J = 150°C	1.5	-	V
Reverse Current*	I _{R1}	$@V_R = rated V_{R,} T_J = 25^{\circ}C$	0.08	25	uA
	I _{R2}	$@V_R = rated V_R, T_J = 125^{\circ}C$	197	500	uA
	I _{R3}	$@V_R = rated V_{R,} T_J = 150^{\circ}C$	850	-	uA
Reverse Recovery Time	t _{rr1}	I _F =500mA,I _R =1A,and I _m =250mA, _, T _J =25°C	36	40	ns
Reverse Recovery Time	t _{rr}		44	-	ns
Reverse Recovery Charge	Qrr	l _F = 60A, diF/dt = -1000A/µs VR = 400V, TJ = 25°C	194	-	nC
Reverse Recovery Current	I _{RRM}	VR = 400V; 1j = 23 C	8.8	-	А
Reverse Recovery Time	t _{rr}		169	-	ns
Reverse Recovery Charge	Qrr	I _F = 60A, diF/dt = -1000A/µs VR = 400V. T₁ = 125°C	1217	-	nC
Reverse Recovery Current	IRRM	- VR - 400V; 1j - 123 C	14.4	-	А
Reverse Recovery Time	t _{rr}		86	-	ns
Reverse Recovery Charge	Qrr	I _F = 30A, diF/dt = -200A/μs VR = 400V. T₁ = 25°C	206	-	nC
Reverse Recovery Current	I _{RRM}	- VR - 400V; 1J - 25 C	4.8	-	А
Reverse Recovery Time	t _{rr}		148	-	ns
Reverse Recovery Charge	Qrr	$I_{\rm F} = 30$ A, diF/dt = -200A/µs	562	-	nC
Reverse Recovery Current	IRRM	VR = 400V, T _J = 125°C	7.6	-	А
Reverse Recovery Time	t _{rr}		27	-	ns
Reverse Recovery Charge	Qrr	I _F = 1A, diF/dt = -100A/μs	20	_	nC
Reverse Recovery Current	I _{RRM}	- VR = 30V, T _J = 25°C	1.5	-	A

 $^{\star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

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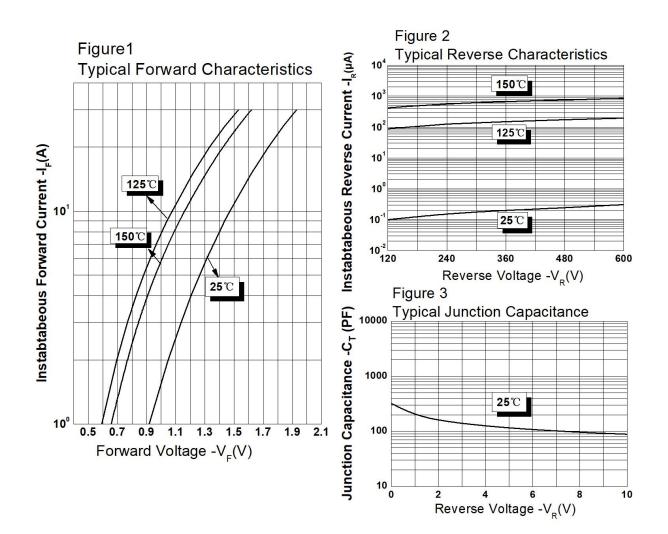
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Technical Data

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Ratings and Characteristics Curves





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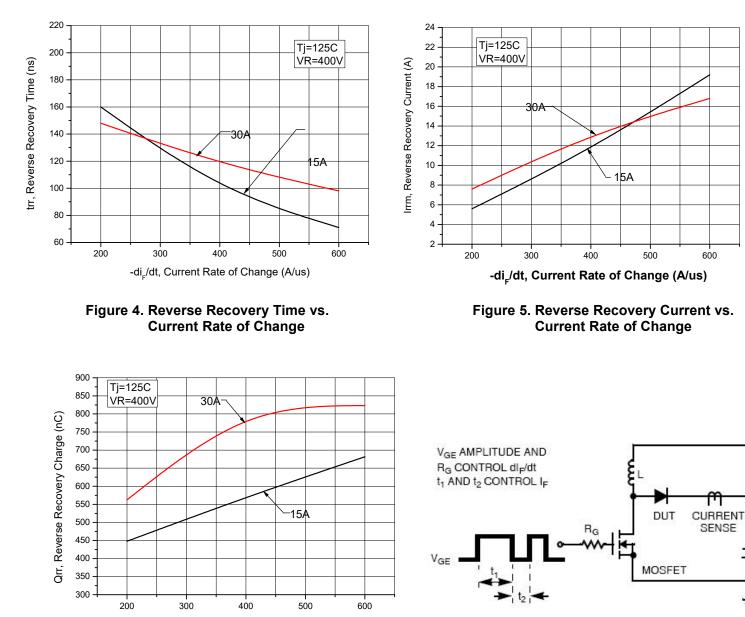


Figure 6. Reverse Recovery Charge vs. Current Rate of Change

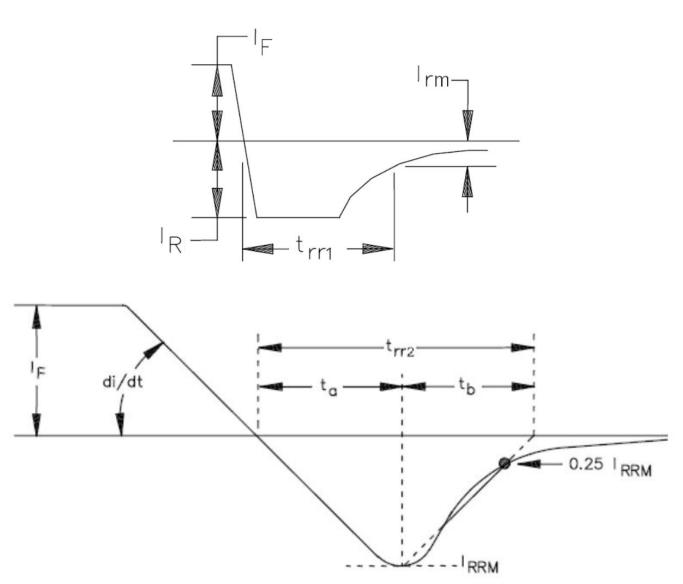
-di_/dt, Current Rate of Change (A/us)

Figure 7. Diode Test Circuit

VDD



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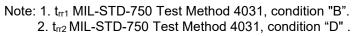


Figure 8 - Reverse Recovery Waveform

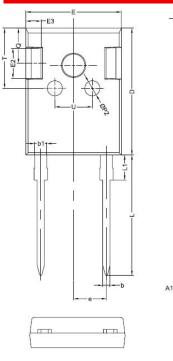


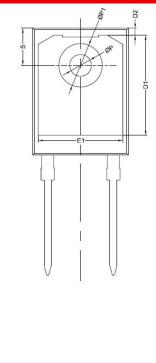
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Mechanical Dimensions TO-247AC

A2





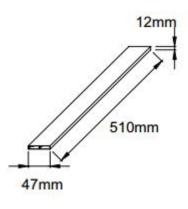
	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
A	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.35		
b1	1.80	2.00	2.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.58			
D2		1.17			
E	15.60	15.80	16.00		
E1		14.02			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.42		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1	7.19	7.40		
P2		2.50			
Q		5.80			
P2 Q S	6.05	6.15	6.25		
Т		10.00			
U		6.20			

Ordering Information

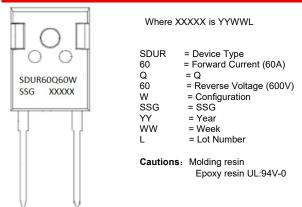
Device	Package	Plating	Shipping	
SDUR60Q60W	TO-247AC(Pb-Free)	Pure Sn	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification



Marking Diagram



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